

SSCE7V022L1

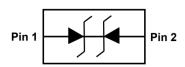
1-line Bidirectional Micro Packaged TVS Diodes for ESD Protection

Description

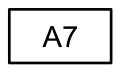
The SSCE7V022L1 is designed with Punch-Through process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

PIN configuration



Top view



Marking

Applications

- ♦ DVI & HDMI Port Protection
- ♦ Serial and Parallel Ports
- ♦ Projection TV
- Notebooks, Desktops, Servers
- ♦ Portable instrumentation

Feature

- ♦ 100W peak pulse power (t_P = 8/20µs)
- ♦ DFN0603-2L Package
- ♦ Working voltage: 7V
- Low clamping voltage
- ♦ Low capacitance
- ♦ Low leakage current
- ♦ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 6A (8/20µs)
- ♦ RoHS Compliant

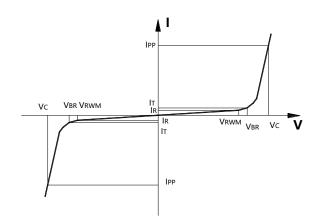
Mechanical data

- ♦ Lead finish:100% matte Sn(Tin)
- ♦ Mounting position: Any
- \diamond Qualified max reflow temperature:260 $^{\circ}$ C
- ♦ Device meets MSL 3 requirements
- ♦ Pure tin plating: 7 ~ 17 um
- ♦ Pin flatness:≤3mil



• Electronic Parameter

Symbol	Parameter		
V_{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I _T		
Ι _Τ	Test Current		
I _{PP}	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P _{PP}	Peak Pulse Power		
Сл	Junction Capacitance		



• Absolute maximum rating @T_A=25℃

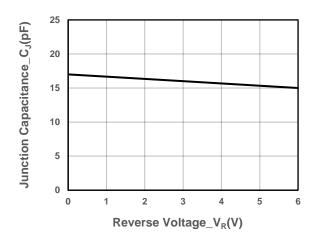
Parameter		Symbol	Value	Unit
Peak Pulse Power(8/20µs)		P _{PP}	100	W
Peak Pulse Current (8/20µs)		I _{PP}	6	Α
ESD Rating per IEC61000-4-2:	Contact		30	147
	Air	V_{ESD}	30	kV
Storage Temperature		T _{STG}	-55/+150	$^{\circ}$
Operating Temperature		TJ	-55/+125	$^{\circ}$

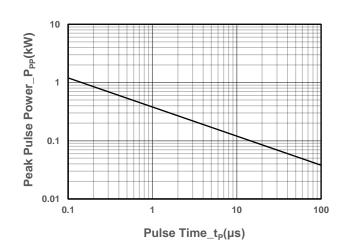
• Electrical Characteristics @T_A=25℃

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Peak Reverse Working Voltage	V_{RWM}				7	V
Breakdown Voltage	V_{BR}	I⊤ = 1mA	7.65		8.9	V
Reverse Leakage Current	I _R	V _{RWM} = 7V			0.1	μA
Clamping Voltage	Vc	$I_{PP} = 1A$, $t_P = 8/20 \mu s$			10	V
Clamping Voltage	Vc	$I_{PP} = 6A$, $t_P = 8/20 \mu s$		11	17	V
Junction Capacitance	CJ	$V_R = 0V$, $f = 1MHz$		17		pF



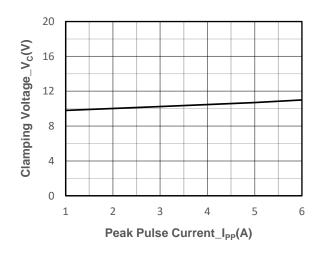
Typical Performance Characteristics

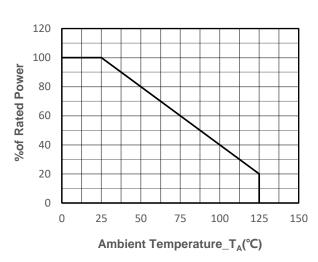




Junction Capacitance vs. Reverse Voltage

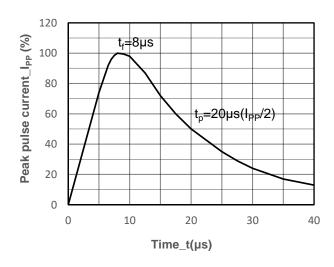






Clamping Voltage vs. Peak Pulse Current

Power derating vs. Ambient temperature



8/20µs Pulse Waveform



Package Information

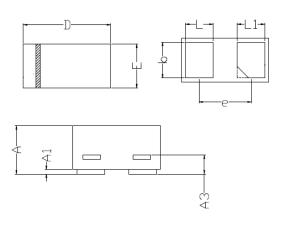
Ordering Information

Device	Package	Qty per Reel	Reel Size
SSCE7V022L1	DFN0603-2L	15000	7 Inch

Mechanical Data

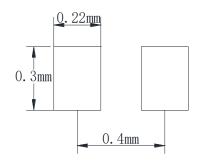
Case:DFN0603-2L

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters			
DIN	Min	Max		
Α	0.230	0.330		
A 1	0.000	0.050		
А3	0.102REF			
D	0.550	0.650		
E	0.250	0.350		
b	0.215	0.275		
L	0.12	0.23		
L1	0.12	0.23		
е	0.40BSC			

Recommended Pad outline





DISCLAIMER

AFSEMI RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. AFSEMI DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICIENCE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

THE GRAPHS PROVIDED IN THIS DOCUMENT ARE STATISTICAL SUMMARIES BASED ON A LIMITED NUMBER OF SAMPLES AND ARE PROVIDED FOR INFORMATIONAL PURPOSE ONLY. THE PERFORMANCE CHARACTERISTICS LISTED IN THEM ARE NOT TESTED OR GUARANTEED. IN SOME GRAPHS, THE DATA PRESENTED MAY BE OUTSIDE THE SPECIFIED OPERATING RANGE (E.G,. OUTSIDE SPECIFIED POWER SUPPLY RANGE) AND THEREFORE OUTSIDE THE WARRANTED RANGE.